## Thermally-Enhanced High Power RF LDMOS FETs <br> 240 W, 1805 - 1880 MHz

## Description

The PTFB182503EL and PTFB182503FL are 240-watt LDMOS FETs intended for use in multi-standard cellular power amplifier applications in the 1805 to 1880 MHz frequency band. Features include input and output matching, high gain, wide signal bandwidth and reduced memory effects for improved DPD correctability. Manufactured with Infineon's advanced LDMOS process, these devices provide excellent thermal performance and superior reliability.


PTFB182503EL H-33288-6

PTFB182503FL H-34288-4/2


## Features

- Broadband internal input and output matching
- Enhanced for use in DPD error correction systems
- Typical two-carrier WCDMA performance,
$1880 \mathrm{MHz}, 30 \mathrm{~V}$
- Average output power $=50 \mathrm{~W}$
- Linear gain = 19 dB
- Drain efficiency = 28 \%
- Intermodulation distortion $=-35 \mathrm{dBc}$
- Typical CW performance, $1880 \mathrm{MHz}, 30 \mathrm{~V}$
- Output power at $P_{1 d B}=240 \mathrm{~W}$
- Efficiency = 55\%
- Increased negative gate-source voltage range for improved performance in Doherty peaking amplifiers
- Integrated ESD protection. Human Body Model, Class 2 (minimum)
- Capable of handling 10:1 VSWR @ $30 \mathrm{~V}, 240$ W (CW) output power
- Pb-free, RoHS compliant


## RF Characteristics

Two-carrier WCDMA Specifications (tested in Infineon test fixture)
$\mathrm{V}_{\mathrm{DD}}=30 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=1.85 \mathrm{~A}$, Pout $=50 \mathrm{~W}$ average
$f_{1}=1840 \mathrm{MHz}, f_{2}=1845 \mathrm{MHz}$, 3GPP signal, channel bandwidth $=3.84 \mathrm{MHz}$, peak/average $=7.5 \mathrm{~dB} @ 0.01 \%$ CCDF

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Gain | $\mathrm{G}_{\mathrm{ps}}$ | 18 | 19 | - | dB |
| Drain Efficiency | $\eta \mathrm{D}$ | 27 | 28 | - | $\%$ |
| Intermodulation Distortion | IMD | - | -35 | -31 | dBc |

## All published data at $T_{\text {CASE }}=25^{\circ} \mathrm{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device-observe handling precautions!

PTFB182503EL PTFB182503FL

## RF Characteristics (cont.)

Two-tone Specifications (not subject to production test-verified by design/characterization in Infineon test fixture) $\mathrm{V}_{\mathrm{DD}}=30 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=1.85 \mathrm{~A}, \mathrm{P}_{\mathrm{OUT}}=220 \mathrm{~W}$ PEP, $f=1840 \mathrm{MHz}$, tone spacing $=1 \mathrm{MHz}$

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Gain | $G_{p s}$ | - | 18 | - | dB |
| Drain Efficiency | $\eta \mathrm{D}$ | - | 40 | - | $\%$ |
| Intermodulation Distortion | IMD | - | -28 | - | dBc |

## DC Characteristics

| Characteristic | Conditions | Symbol | Min | Typ | Max | Unit |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| Drain-Source Breakdown Voltage | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{DS}}=10 \mathrm{~mA}$ | $\mathrm{~V}_{(\mathrm{BR}) \mathrm{DSS}}$ | 65 | - | - | V |
| Drain Leakage Current | $\mathrm{V}_{\mathrm{DS}}=28 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{DSS}}$ | - | - | 1.0 | $\mu \mathrm{~A}$ |
| Drain Leakage Current | $\mathrm{V}_{\mathrm{DS}}=63 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{DSS}}$ | - | - | 10.0 | $\mu \mathrm{~A}$ |
| On-State Resistance | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0.1 \mathrm{~V}$ | $\mathrm{R}_{\mathrm{DS}(\mathrm{on})}$ | - | 0.03 | - | $\Omega$ |
| Operating Gate Voltage | $\mathrm{V}_{\mathrm{DS}}=30 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=1.85 \mathrm{~A}$ | $\mathrm{~V}_{\mathrm{GS}}$ | 2.3 | 2.8 | 3.3 | V |
| Gate Leakage Current | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{GSS}}$ | - | - | 1.0 | $\mu \mathrm{~A}$ |

## Maximum Ratings

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Drain-Source Voltage | $\mathrm{V}_{\mathrm{DSS}}$ | 65 | V |
| Gate-Source Voltage | $\mathrm{V}_{\mathrm{GS}}$ | -6 to +10 | V |
| Operating Voltage | $\mathrm{V}_{\mathrm{DD}}$ | 24 to 30 | V |
| Junction Temperature | $\mathrm{TJ}_{J}$ | 200 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {STG }}$ | -40 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Resistance $\left(\mathrm{T}_{\text {CASE }}=70^{\circ} \mathrm{C}, 50 \mathrm{~W}\right.$ WCDMA) | $\mathrm{R}_{\theta \mathrm{JC}}$ | 0.262 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## Ordering Information

| Type and Version | Order Code | Package Description | Shipping |
| :--- | :--- | :--- | :--- |
| PTFB182503EL V1 R0 | PTFB182503ELV1R0XTMA1 | H-33288-6, slotted flange | Tape \& Reel, 50 pcs |
| PTFB182503EL V1 R250 | PTFB182503ELV1R250XTMA1 | H-33288-6, slotted flange | Tape \& Reel, 250 pcs |
| PTFB182503FL V2 R0 | PTFB182503FLV2R0XTMA1 | H-34288-4/2, earless flange | Tape \& Reel, 50 pcs |
| PTFB182503FL V2 R250 | PTFB182503FLV2R250XTMA1 | H-34288-4/2, earless flange | Tape \& Reel, 250 pcs |

## PTFB182503EL PTFB182503FL

Typical Performance (data taken in a production test fixture)



CW Performance
Gain \& Efficiency vs. Output Power
$\mathrm{V}_{\mathrm{DD}}=30 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=1.85 \mathrm{~A}, f=1842 \mathrm{MHz}$


Power Sweep
$\mathrm{V}_{\mathrm{DD}}=30 \mathrm{~V}, f=1842 \mathrm{MHz}$


PTFB182503EL PTFB182503FL

## Typical Performance (cont.)



## Broadband Circuit Impedance



| Frequency | Z Source $\Omega$ |  | Z Load $\Omega$ |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathbf{M H z}$ | $\mathbf{R}$ | $\mathbf{j X}$ | $\mathbf{R}$ | $\mathbf{j X}$ |
| 1780 | 2.99 | -2.48 | 1.33 | -0.49 |
| 1800 | 2.95 | -2.30 | 1.33 | -0.38 |
| 1820 | 2.89 | -2.13 | 1.31 | -0.27 |
| 1840 | 2.84 | -1.96 | 1.29 | -0.16 |
| 1860 | 2.80 | -1.76 | 1.29 | -0.02 |
| 1880 | 2.78 | -1.58 | 1.28 | 0.10 |
| 1900 | 2.74 | -1.39 | 1.29 | 0.23 |
| 1920 | 2.72 | -1.21 | 1.29 | 0.36 |

## Reference Circuit



Reference circuit input schematic for $f=1880 \mathrm{MHz}$


Reference circuit output schematic for $f=1880 \mathrm{MHz}$

PTFB182503EL PTFB182503FL

## Reference Circuit (cont.)

## Description

| DUT | PTFB182503EL or PTFB182503FL |
| :--- | :--- |
| PCB | $0.76 \mathrm{~mm}[.030 "]$ thick, $\varepsilon \mathrm{\varepsilon r}=3.48$, Rogers 4350, 1 oz. copper |

## Electrical Characteristics at 1880 MHz

| Transmission Line | Electrical <br> Characteristics | Dimensions: mm | Dimensions: mils |
| :---: | :---: | :---: | :---: |
| Input |  |  |  |
| TL101, TL117 | $0.022 \lambda, 78.27 \Omega$ | W = 0.762, L= 2.159 | W = 30, L = 85 |
| TL102 | $0.035 \lambda, 51.58 \Omega$ | $\mathrm{W}=1.651, \mathrm{~L}=3.358$ | $\mathrm{W}=65, \mathrm{~L}=132$ |
| TL103 | $0.050 \lambda, 9.67 \Omega$ | $\mathrm{W}=13.970, \mathrm{~L}=4.445$ | $\mathrm{W}=550, \mathrm{~L}=175$ |
| TL104 | $0.031 \lambda, 51.58 \Omega$ | W = 1.651, L= 3.018 | $\mathrm{W}=65, \mathrm{~L}=119$ |
| TL105 |  | $\begin{aligned} & \mathrm{W} 1=13.970, \mathrm{~W} 2=0.762, \mathrm{~W} 3=13.970, \\ & \mathrm{~W} 4=0.762 \end{aligned}$ | $\begin{aligned} & \mathrm{W} 1=550, \mathrm{~W} 2=30, \mathrm{~W} 3=550 \\ & \mathrm{~W} 4=30 \end{aligned}$ |
| TL106, TL107 |  | $\mathrm{W}=0.762$ | $\mathrm{W}=30$ |
| TL108, TL136 | $0.010 \lambda, 68.02 \Omega$ | $\mathrm{W} 1=1.016, \mathrm{~W} 2=1.016, \mathrm{~W} 3=1.016$ | $\mathrm{W} 1=40, \mathrm{~W} 2=40, \mathrm{~W} 3=40$ |
| $\begin{aligned} & \text { TL109, TL110, TL132, } \\ & \text { TL139 } \end{aligned}$ | $0.010 \lambda, 78.27 \Omega$ | $\mathrm{W} 1=0.762, \mathrm{~W} 2=0.762, \mathrm{~W} 3=1.016$ | $\mathrm{W} 1=30, \mathrm{~W} 2=30, \mathrm{~W} 3=40$ |
| TL111 |  | $\mathrm{W} 1=1.651, \mathrm{~W} 2=2.032$ | $\mathrm{W} 1=65, \mathrm{~W} 2=80$ |
| TL112, TL134 | $0.014 \lambda, 38.82 \Omega$ | $\mathrm{W}=2.540, \mathrm{~L}=1.321$ | $\mathrm{W}=100, \mathrm{~L}=52$ |
| TL113 | $0.020 \lambda, 78.27 \Omega$ | $\mathrm{W}=0.762, \mathrm{~L}=2.007$ | W = 30, L = 79 |
| TL114 | $0.099 \lambda, 92.53 \Omega$ | W = 0.508, L = 9.957 | $\mathrm{W}=20, \mathrm{~L}=392$ |
| TL115 | $0.016 \lambda, 68.02 \Omega$ | $\mathrm{W}=1.016, \mathrm{~L}=1.524$ | W = 40, L=60 |
| TL116, TL137 | $0.017 \lambda, 78.27 \Omega$ | $\mathrm{W}=0.762, \mathrm{~L}=1.727$ | $\mathrm{W}=30, \mathrm{~L}=68$ |
| TL118, TL119 | $0.001 \lambda, 68.02 \Omega$ | $\mathrm{W}=1.016, \mathrm{~L}=0.127$ | W = 40, L = 5 |
| TL120, TL121 | $0.013 \lambda, 78.27 \Omega$ | $\mathrm{W}=0.762, \mathrm{~L}=1.270$ | $\mathrm{W}=30, \mathrm{~L}=50$ |
| TL122 | $0.022 \lambda, 9.67 \Omega$ | $\mathrm{W}=13.970, \mathrm{~L}=1.981$ | $\mathrm{W}=550, \mathrm{~L}=78$ |
| TL123, TL124 | $0.007 \lambda, 68.02 \Omega$ | W = 1.016, L = 0.686 | W = 40, L = 27 |
| TL125, TL126 | $0.118 \lambda, 78.27 \Omega$ | $\mathrm{W}=0.762, \mathrm{~L}=11.684$ | $\mathrm{W}=30, \mathrm{~L}=460$ |
| TL127 | $0.008 \lambda, 45.17 \Omega$ | W = 2.032, L = 0.762 | W = 80, L = 30 |
| TL128 | $0.000 \lambda, 45.17 \Omega$ | W = 2.032, L = 0.025 | $\mathrm{W}=80, \mathrm{~L}=1$ |
| TL129 | $0.023 \lambda, 9.67 \Omega$ | W1 = 13.970, W2 = 13.970, W3 = 2.032 | $\mathrm{W} 1=550, \mathrm{~W} 2=550, \mathrm{~W} 3=80$ |
| TL130 | $0.000 \lambda, 9.67 \Omega$ | $\mathrm{W}=13.970, \mathrm{~L}=0.025$ | W = 550, L = 1 |
| TL131 (taper) | $0.028 \lambda, 9.67 \Omega / 51.58 \Omega$ | W 1 = 13.970, W2 $=1.651, \mathrm{~L}=2.515$ | $\mathrm{W} 1=550, \mathrm{~W} 2=65, \mathrm{~L}=99$ |
| TL133 | $0.050 \lambda, 9.67 \Omega$ | $\mathrm{W}=13.970, \mathrm{~L}=4.470$ | $\mathrm{W}=550, \mathrm{~L}=176$ |
| TL135 | $0.015 \lambda, 68.02 \Omega$ | W = 1.016, L = 1.514 | $W=40, L=60$ |
| TL138 | $0.010 \lambda, 78.27 \Omega$ | $\mathrm{W}=0.762, \mathrm{~L}=0.991$ | $\mathrm{W}=30, \mathrm{~L}=39$ |

table continued on page 7

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## Reference Circuit (cont.)

## Electrical Characteristics at 1880 MHz

| Transmission Line | Electrical <br> Characteristics | Dimensions: mm | Dimensions: mils |
| :---: | :---: | :---: | :---: |
| Output |  |  |  |
| $\begin{aligned} & \text { TL201, TL219, TL220, } \\ & \text { TL222 } \end{aligned}$ |  | $\mathrm{W}=0.002, \mathrm{ANG}=90.000, \mathrm{R}=0.002$ | $\mathrm{W}=2, \mathrm{ANG}=3543307, \mathrm{R}=70$ |
| TL202 |  | $\mathrm{W} 1=1.651, \mathrm{~W} 2=2.032$ | $\mathrm{W} 1=65, \mathrm{~W} 2=80$ |
| TL203 | $0.012 \lambda, 51.58 \Omega$ | $\mathrm{W}=1.651, \mathrm{~L}=1.118$ | $\mathrm{W}=65, \mathrm{~L}=44$ |
| TL204 | $0.084 \lambda, 6.86 \Omega$ | $\mathrm{W}=20.320, \mathrm{~L}=7.366$ | W = 800, L = 290 |
| TL205 | $0.011 \lambda, 45.17 \Omega$ | $\mathrm{W}=2.032, \mathrm{~L}=1.016$ | W = 80, L = 40 |
| TL206 | $0.028 \lambda, 23.60 \Omega$ | $\mathrm{W}=4.928, \mathrm{~L}=2.540$ | W = 194, L = 100 |
| TL207 | $0.028 \lambda, 23.79 \Omega$ | W = 4.877, L = 2.540 | W = 192, L = 100 |
| TL208 (taper) | $0.018 \lambda, 6.86 \Omega$ / $8.31 \Omega$ | $\mathrm{W} 1=20.320, \mathrm{~W} 2=16.510, \mathrm{~L}=1.575$ | $\mathrm{W} 1=800, \mathrm{~W} 2=650, \mathrm{~L}=62$ |
| TL209, TL210 | $0.076 \lambda, 34.08 \Omega$ | $\mathrm{W}=3.048, \mathrm{~L}=7.112$ | W = 120, L = 280 |
| TL211, TL216, TL224, TL225 | $0.032 \lambda, 34.08 \Omega$ | $\mathrm{W} 1=3.048, \mathrm{~W} 2=3.048, \mathrm{~W} 3=3.048$ | W 1 = 120, W2 = 120, W3 = 120 |
| TL212, TL228, TL217, TL218, TL227 | $0.024 \lambda, 34.08 \Omega$ | $\mathrm{W} 1=3.048, \mathrm{~W} 2=3.048, \mathrm{~W} 3=2.286$ | $\mathrm{W} 1=120, \mathrm{~W} 2=120, \mathrm{~W} 3=90$ |
| TL213 | $0.008 \lambda, 34.08 \Omega$ | $\mathrm{W} 1=3.048, \mathrm{~W} 2=3.048, \mathrm{~W} 3=0.762$ | $W 1=120, W 2=120, W 3=30$ |
| TL214, TL215 | $0.051 \lambda, 34.08 \Omega$ | $\mathrm{W}=3.048, \mathrm{~L}=4.826$ | $\mathrm{W}=120, \mathrm{~L}=190$ |
| TL221, TL242 | $0.013 \lambda, 51.58 \Omega$ | $\mathrm{W}=1.651, \mathrm{~L}=1.270$ | $\mathrm{W}=65, \mathrm{~L}=50$ |
| TL223 (taper) | $0.018 \lambda, 19.45 \Omega / 51.58 \Omega$ | $\mathrm{W} 1=6.248, \mathrm{~W} 2=1.651, \mathrm{~L}=1.651$ | $\mathrm{W} 1=246, \mathrm{~W} 2=65, \mathrm{~L}=65$ |
| TL226 |  | $\mathrm{W} 1=12.700, \mathrm{~W} 2=17.780$ | $\mathrm{W} 1=500, \mathrm{~W} 2=700$ |
| TL229, TL230 | $0.000 \lambda, 19.45 \Omega$ | $\mathrm{W}=6.248, \mathrm{~L}=0.025$ | W = 246, L = 1 |
| TL231 (taper) | $0.038 \lambda, 8.31 \Omega / 19.45 \Omega$ | $\mathrm{W} 1=16.510, \mathrm{~W} 2=6.248, \mathrm{~L}=3.378$ | $\mathrm{W} 1=650, \mathrm{~W} 2=246, \mathrm{~L}=133$ |
| TL232 |  | $\begin{aligned} & \mathrm{W} 1=6.248, \mathrm{~W} 2=0.025, \mathrm{~W} 3=6.248, \\ & \mathrm{~W} 4=0.025 \end{aligned}$ | $\begin{aligned} & \mathrm{W} 1=246, \mathrm{~W} 2=1, \mathrm{~W} 3=246, \\ & \mathrm{~W} 4=1 \end{aligned}$ |
| $\begin{aligned} & \text { TL233, TL234, TL237, } \\ & \text { TL238 } \end{aligned}$ | $0.000 \lambda, 146.88 \Omega$ | $\mathrm{W}=0.025, \mathrm{~L}=0.025$ | $\mathrm{W}=1, \mathrm{~L}=1$ |
| TL235 | $0.005 \lambda, 51.58 \Omega$ | $\mathrm{W}=1.651, \mathrm{~L}=0.508$ | W = 65, L= 20 |
| $\begin{aligned} & \hline \text { TL236 } \\ & \text { TL239 } \end{aligned}$ | $0.000 \lambda, 8.31 \Omega$ | $\begin{aligned} & \mathrm{W}=16.510, \mathrm{~L}=0.025 \\ & \mathrm{~W} 1=20.320, \mathrm{~W} 2=0.025, \mathrm{~W} 3=20.320 \\ & \mathrm{~W} 4=0.025 \end{aligned}$ | $\begin{aligned} & W=650, L=1 \\ & W 1=800, W 2=1, W 3=800, \\ & W 4=1 \end{aligned}$ |
| TL240, TL241 | $0.000 \lambda, 6.86 \Omega$ | $\mathrm{W}=20.320, \mathrm{~L}=0.025$ | W = 800, L= 1 |

PTFB182503EL PTFB182503FL

## Reference Circuit (cont.)

## Circuit Assembly Information

Test Fixture Part No. LTN/PTFB182503EF
Find Gerber files for this test fixture on the Infineon Web site at http://www.infineon.com/rfpower


[^0]PTFB182503EL PTFB182503FL

## Reference Circuit (cont.)

| Component | Description | Suggested Manufacturer | P/N |
| :---: | :---: | :---: | :---: |
| Input |  |  |  |
| C101 | Chip capacitor, 7.5 pF | ATC | ATC100B7R5BW500XB |
| C102, C103 | Chip capacitor, $4.71 \mu \mathrm{~F}$ | ATC | 493-2372-2-ND |
| C104 | Chip capacitor, 0.3 pF | ATC | ATC100A0R3BW150XB |
| C105, C106 | Chip capacitor, 10 pF | ATC | ATC100A100FW150XB |
| C801, C802, C803 | Capacitor, 1000 pF | Digi-Key | PCC1772CT-ND |
| R101, R102, R804, R805 | Resistor, $10 \Omega$ | Digi-Key | P10ECT-ND |
| R801 | Resistor, $1300 \Omega$ | Digi-Key | P1.3KGCT-ND |
| R802 | Resistor, $1200 \Omega$ | Digi-Key | P1.2KGCT-ND |
| R803 | Resistor, $100 \Omega$ | Digi-Key | P100ECT-ND |
| S1 | Potentiometer, $2 \mathrm{k} \Omega$ | Digi-Key | 3224W-202ECT-ND |
| S2 | Transistor | Digi-Key | BCP5616TA-ND |
| S3 | Voltage Regulator | Digi-Key | LM78L05ACM-ND |
| Output |  |  |  |
| C201, C203 | Chip capacitor, $0.1 \mu \mathrm{~F}$ | Digi-Key | 445-1411-2-ND |
| C202, C204 | Capacitor, $10 \mu \mathrm{~F}$ | Garrett Electronics | 281M5002106K |
| C205, C206 | Chip capacitor, 0.6 pF | ATC | ATC100B0R6BW500XB |
| C207, C208 | Chip capacitor, $10 \mu \mathrm{~F}$ | Digi-Key | 587-1818-2-ND |
| C209, C210 | Chip capacitor, $0.1 \mu \mathrm{~F}$ | Digi-Key | 399-1267-2-ND |
| C211, C212 | Chip capacitor, 0.9 pF | ATC | ATC100B0R9BW500XB |
| C213, C215 | Chip capacitor, 2.2 ¢ F | Digi-Key | 445-1447-2-ND |
| C214 | Chip capacitor, 10 pF | ATC | ATC100B100FW500XB |

## PTFB182503EL PTFB182503FL

## Package Outline Specifications

## Package H-33288-6



Diagram Notes—unless otherwise specified:

1. Interpret dimensions and tolerances per ASME Y14.5M-1994.
2. Primary dimensions are mm . Alternate dimensions are inches.
3. All tolerances $\pm 0.127$ [0.005] unless specified otherwise.
4. Pins: D - drain; G - gate; S - source; V - $V_{D D}$; $E, F-N . C$.
5. Lead thickness: $0.10+0.051 /-0.025 \mathrm{~mm}[0.004+0.002 /-0.001$ inch].
6. Gold plating thickness: 0.25 micron [10 microinch] max.

## PTFB182503EL PTFB182503FL

Package Outline Specifications (cont.)


Find the latest and most complete information about products and packaging at the Infineon Internet page http://www.infineon.com/rfpower

| Revision Histor | $y: \quad$ 2016-06-10 | Data Sheet |
| :---: | :---: | :---: |
| Previous Version | : 2013-08-06, Data Sheet |  |
| Page | Subjects (major changes since last revision) |  |
| 2 | Updated ordering code to R0 |  |
|  |  |  |
|  |  |  |
|  |  |  |
|  |  |  |

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## Edition 2016-06-10

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81726 Munich, Germany
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[^0]:    Reference circuit assembly diagram (not to scale)

